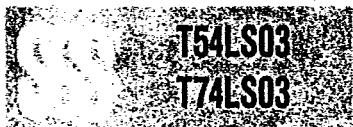


LOW POWER SCHOTTKY

INTEGRATED CIRCUITS

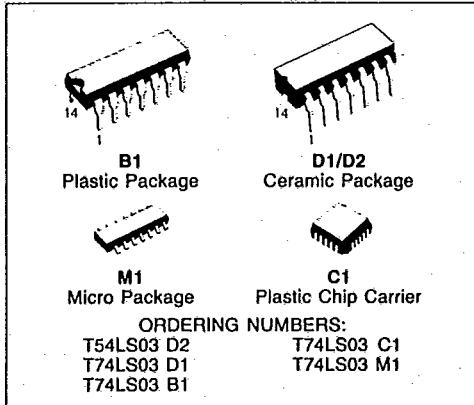


67C 16006 D T-43-15

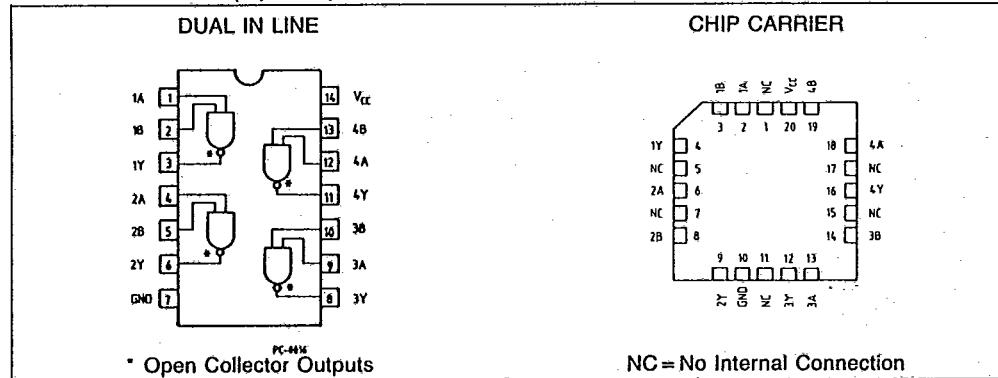
QUAD 2-INPUT NAND GATE

DESCRIPTION

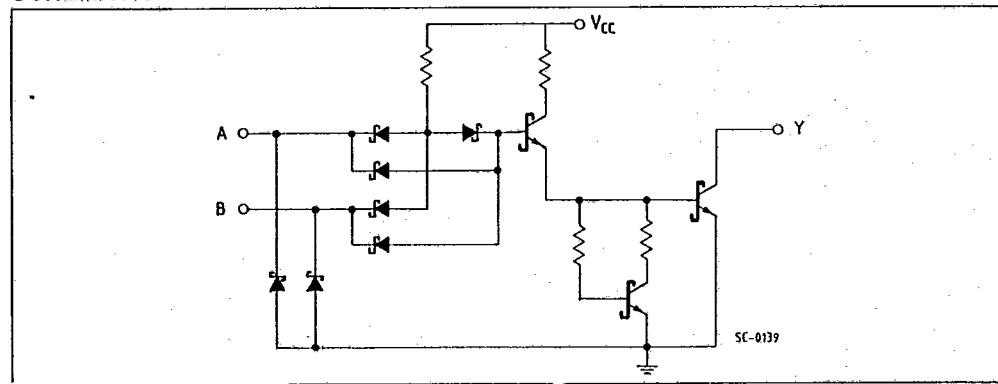
The T54LS03/T74LS03 is a high speed QUAD 2-INPUT NAND GATE fabricated in LOW POWER SCHOTTKY technology.



PIN CONNECTION (top view)



SCHEMATIC



T54LS03

T74LS03

67C 16007 DT-43-15

LOGIC DIAGRAM AND TRUTH TABLE

A	B	Y
L	X	H
X	L	H
H	H	L

L = LOW Voltage Level
 H = HIGH Voltage Level
 X = Don't Care

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to 7	V
V _I	Input Voltage, Applied to Input	-0.5 to 15	V
V _O	Output Voltage, Applied to Output	0 to 10	V
I _I	Input Current, Into Inputs	-30 to 5	mA
I _O	Output Current, Into Outputs	50	mA

Stresses in excess of those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions in excess of those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

GUARANTEED OPERATING RANGES

Part Numbers	Supply Voltage			Temperature
	Min	Typ	Max	
T54LS03D2	4.5 V	5.0 V	5.5 V	-55°C to +125°C
T74LS03XX	4.75 V	5.0 V	5.25 V	0°C to +70°C

XX = package type.

T54LS03

T74LS03

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE

Symbol	Parameter	Limits			Test Conditions (Note 1)	Units
		Min.	Typ.	Max.		
V _{IH}	Input HIGH Voltage	2.0			Guaranteed input HIGH Voltage	V
V _{IL}	Input LOW Voltage	54		0.7	Guaranteed input LOW Voltage	V
		74		0.8		
V _{CD}	Input Clamp Diode Voltage		-0.65	-1.5	V _{CC} = MIN, I _{IN} = -18mA	V
I _{OH}	Output HIGH Current	54,74		100	V _{CC} = MIN, V _{OH} = 5.5V, V _{IN} = V _{IL}	μA
V _{OL}	Output LOW Voltage	54,74	0.25	0.4	I _{OL} = 4.0mA	V
		74	0.35	0.5	I _{OL} = 8.0mA	
I _{IH}	Input HIGH Current			20	V _{CC} = MAX, V _{IN} = 2.7V	μA
				0.1	V _{CC} = MAX, V _{IN} = 7.0V	mA
I _{IL}	Input LOW Current			-0.4	V _{CC} = MAX, V _{IN} = 0.4V	mA
I _{CCH}	Supply Current HIGH			1.6	V _{CC} = MAX, V _{IN} = 0V	mA
I _{CCL}	Supply Current LOW			4.4	V _{CC} = MAX, Inputs Open	mA

AC CHARACTERISTICS: T_A = 25°C (See page 576 for AC test circuit and waveforms)

Symbol	Parameter	Limits			Test Conditions	Units
		Min.	Typ.	Max.		
t _{PLH}	Turn Off Delay, Input to Output		17	32	V _{CC} = 5.0V	ns
t _{PHL}	Turn On Delay, Input to Output		15	28	C _L = 15pF, R _L = 2.0kΩ	ns

Notes:

- 1) For conditions shown as MIN or MAX, use the appropriate value specified under guaranteed operating ranges.
- 2) Typical values are at V_{CC} = 5.0V, T_A = 25°C.

S G S-THOMSON D7E D
67C 16544

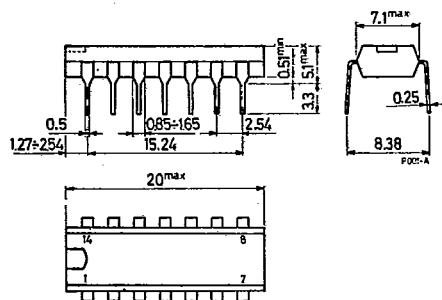
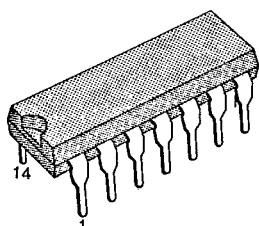
7929237 0016415 6

D

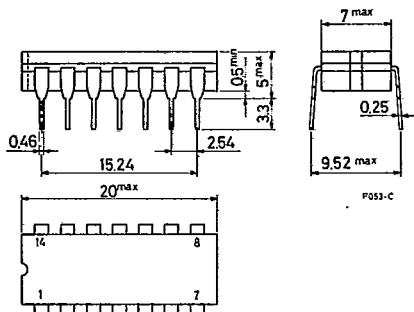
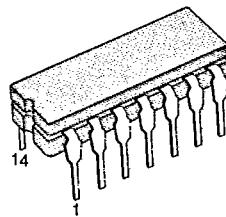
T-90-20

Packages

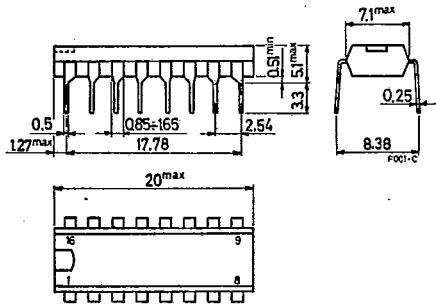
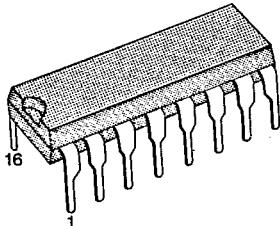
14-LEAD PLASTIC DIP



14-LEAD CERAMIC DIP



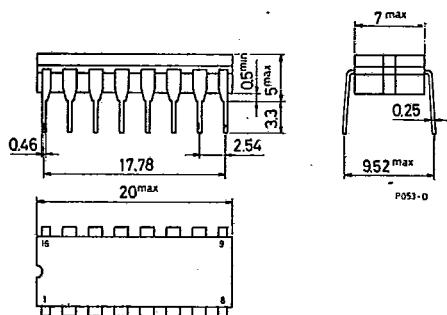
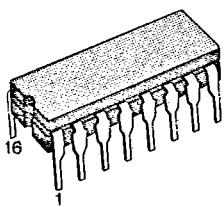
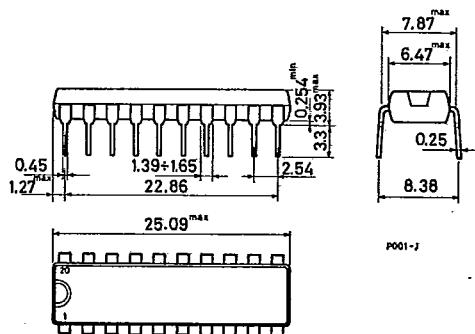
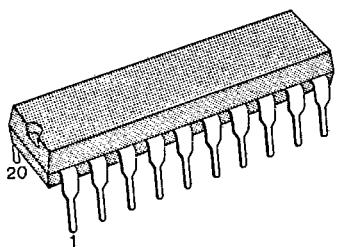
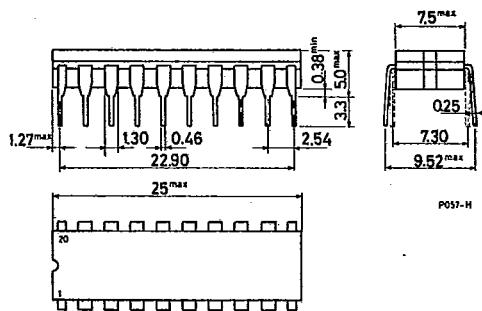
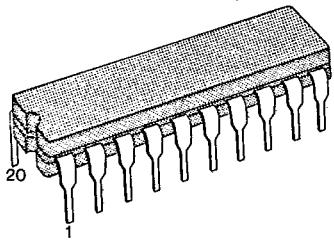
16-LEAD PLASTIC DIP



Packages

67C 16545 D

T-90-20

16-LEAD CERAMIC DIP**20-LEAD PLASTIC DIP****20-LEAD CERAMIC DIP**

S G S-THOMSON

07E D ■ 7929237 0016417 T ■

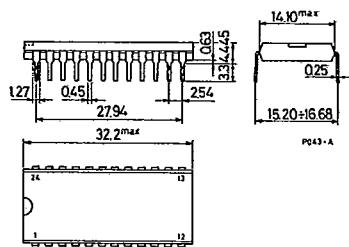
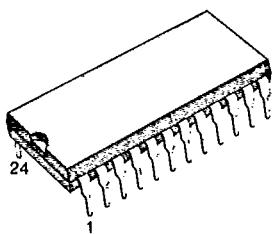
67C 16546

D

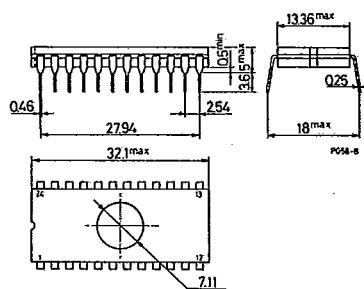
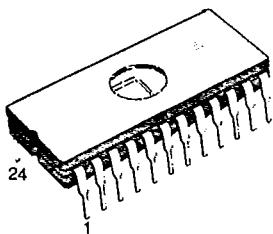
T-90-20

Packages

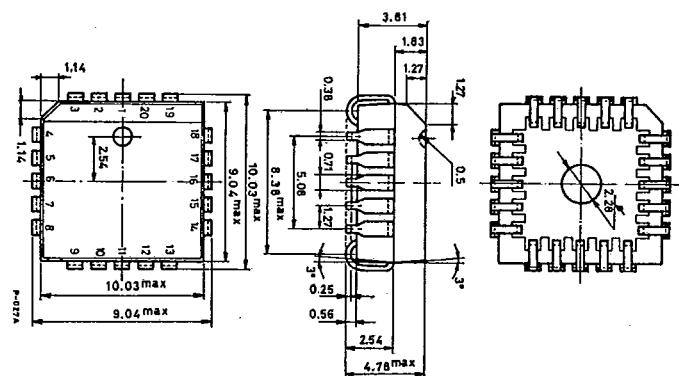
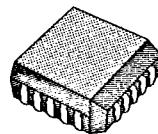
24-LEAD PLASTIC DIP



24-LEAD CERAMIC DIP



CHIP CARRIER 20 LEAD PLASTIC



0608

B-01

583

S G S-THOMSON

07E D

7929237 0016418 1

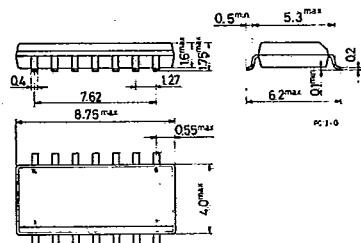
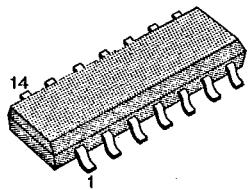
Packages

67C 16547

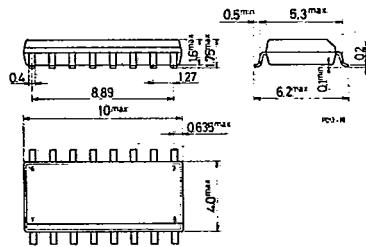
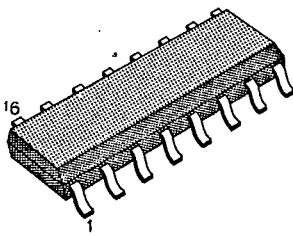
D

T-90-20

14-LEAD PLASTIC DIP MICROPACKAGE



16-LEAD PLASTIC DIP MICROPACKAGE



NOTE: FOR 20-LEAD PLASTIC DIP MICROPACKAGE CONTACT SGS

Surface Mounted

67C 16548

D

T-90-20

One possible solution to the important problem of PWB minimization, is that of using surface mounted components. Integrated circuits in SO (Small Outline) packages are made up of standard chips mounted in very small plastic packages.

The advantages given by using these devices are:

PWB Reduction

This is by far the most important advantage since the reduction of PWB size varies from 40 to 60% in comparison with standard board types. (See page 584 for package dimensions.)

Assembly Cost Reduction

SO Devices require no preliminary operation prior to mounting and can therefore be easily utilized in fully automatic equipment.

Increasing Reliability

The following characteristics lead to a higher level of reliability with respect to their standard packaged counter parts:

- The mounting system is fully automatic
- PWB number and the interconnections between them are reduced when the same number of devices are used.
- The high density of components on the board makes it thermally much more stable.

Noise Reduction and Improved Frequency Response

The reduction of the length of the connecting wires between the leads and the silicon guarantees a more homogeneous propagation delay between the external pins, with respect to the standard type.

Assembly Without Board Holes

The devices are placed on the board and soldered. This technology permits a higher level of tolerance in the positioning (automatic) of the device. For the standard DIP types this must be done with great accuracy due to the insertion of the leads into their holes.

